

DATA SHEET

74ALVT16344

2.5V/3.3V 1-to-4 address driver (3-State)

Product specification

1998 Jun 30

IC24 Data Handbook

2.5V/3.3V 1-to-4 address driver (3-State)**74ALVT16344****FEATURES**

- Multiple V_{CC} and GND pins minimize switching noise
- 5V I/O Compatible
- Live insertion/extraction permitted
- 3-State output buffers
- Power-up 3-State
- Output capability: +64mA/-32mA
- Latch-up protection exceeds 500mA per Jedec JC40.2 Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model

DESCRIPTION

The 74ALVT16344 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive. It is designed for V_{CC} operation at 2.5V or 3.3V with I/O compatibility to 5V.

The 74ALVT16344 is a 1-to-4 address driver used in applications where four separate memory locations must be addressed by a single address.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C	TYPICAL		UNIT
			2.5V	3.3V	
t _{PLH} t _{PHL}	Propagation delay nAx to nBx or nBx to nAx	C _L = 50pF	2.5 1.9	1.9 1.6	ns
C _{IN}	Input capacitance DIR, OE	V _I = 0V or V _{CC}	3	3	pF
C _{Out}	Output capacitance	V _{I/O} = 0V or V _{CC}	9	9	pF
I _{CCZ}	Total supply current	Outputs disabled	40	70	μA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic SSOP Type III	-40°C to +85°C	74ALVT16344 DL	AV16344 DL	SOT371-1
56-Pin Plastic TSSOP Type II	-40°C to +85°C	74ALVT16344 DGG	AV16344 DGG	SOT364-1

PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
8, 14, 15, 21, 36, 42, 43, 49	nA	Data inputs
2, 3, 5, 6, 9, 10, 12, 13, 16, 17, 19, 20, 23, 24, 26, 27, 30, 31, 33, 34, 37, 38, 40, 44, 45, 47, 48, 51, 52, 54, 55	nY _X	Data outputs
1, 28, 29, 56	OE	Output enable inputs (active-Low)
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage

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PIN CONFIGURATION

OE1	1		OE4	56
1Y0	2		8Y0	55
1Y1	3		8Y1	54
GND	4		GND	53
1Y2	5		8Y2	52
1Y3	6		8Y3	51
V _{CC}	7		V _{CC}	50
1A	8		8A	49
2Y0	9		7Y0	48
2Y1	10		7Y1	47
GND	11		GND	46
2Y2	12		7Y2	45
2Y3	13		7Y3	44
2A	14		7A	43
3A	15		6A	42
3Y0	16		6Y0	41
3Y1	17		6Y1	40
GND	18		GND	39
3Y2	19		6Y2	38
3Y3	20		6Y3	37
4A	21		5A	36
V _{CC}	22		V _{CC}	35
4Y0	23		5Y0	34
4Y1	24		5Y1	33
GND	25		GND	32
4Y2	26		5Y2	31
4Y3	27		5Y3	30
OE2	28		OE3	29

SV01735

FUNCTION TABLE

INPUTS		OUTPUTS	OPERATING MODE
OE	nA	nYx	
L	L	L	Transparent
L	H	H	Transparent
H	X	Z	High impedance

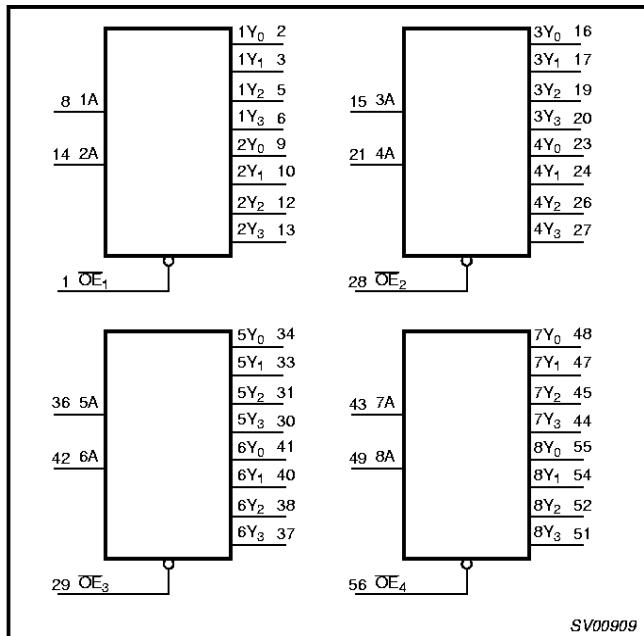
X = Don't care

Z = High impedance "off" state

H = High voltage level

L = Low voltage level

LOGIC SYMBOL

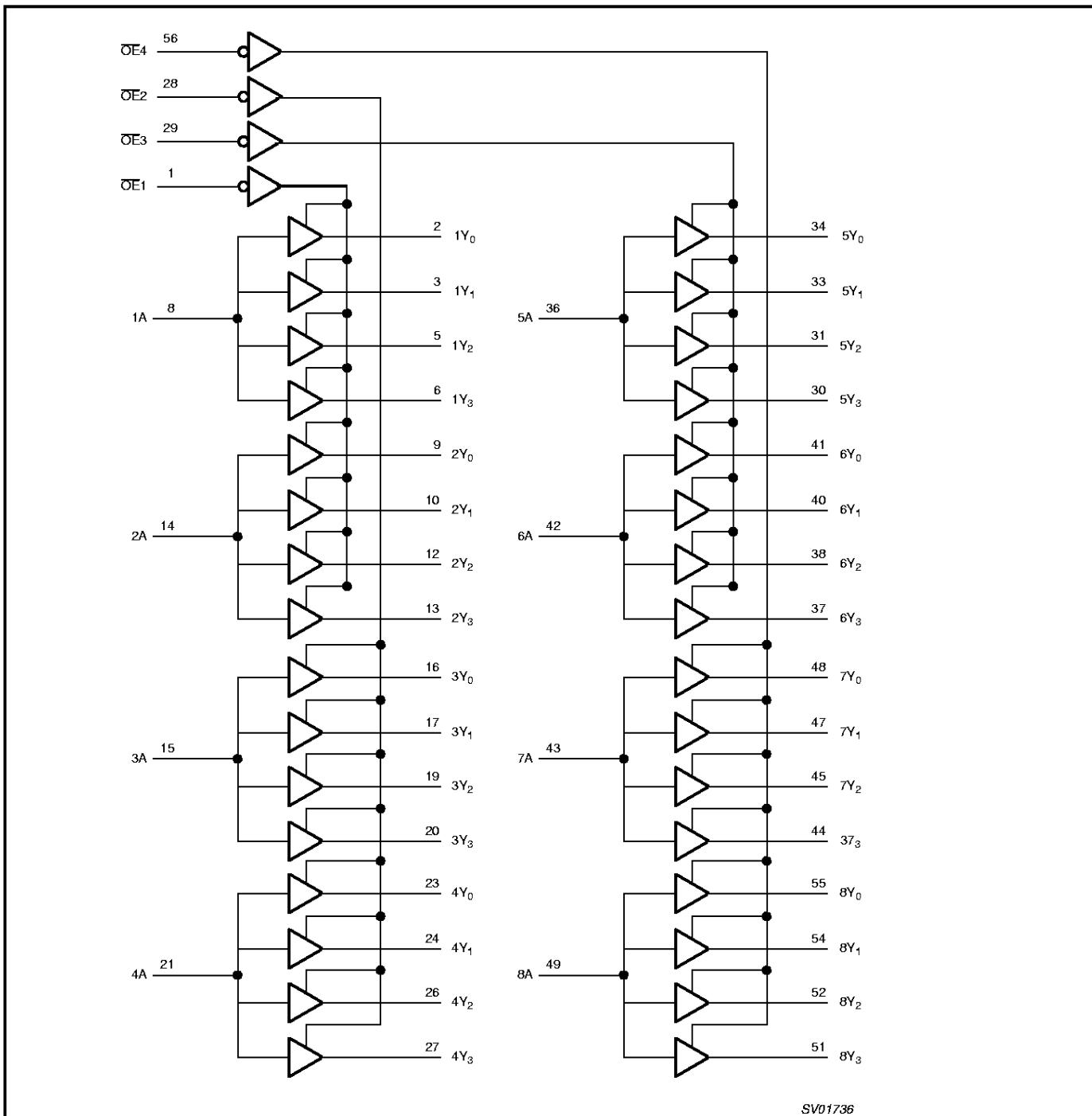


SV00909

2.5V/3.3V 1-to-4 address driver (3-State)

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LOGIC DIAGRAM



SV01736

2.5V/3.3V 1-to-4 address driver (3-State)

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ABSOLUTE MAXIMUM RATINGS^{1,2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
V _I	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
I _{OUT}	DC output current	Output in Low state	128	mA
		Output in High state	-64	
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	2.5V RANGE LIMITS		3.3V RANGE LIMITS		UNIT
		MIN	MAX	MIN	MAX	
V _{CC}	DC supply voltage	2.3	2.7	3.0	3.6	V
V _I	Input voltage	0	5.5	0	5.5	V
V _{IH}	High-level input voltage	1.7		2.0		V
V _{IL}	Input voltage		0.7		0.8	V
I _{OH}	High-level output current		-8		-32	mA
I _{OL}	Low-level output current	8		32		mA
	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		24		64	
Δt/Δv	Input transition rise or fall rate; Outputs enabled		10		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	-40	+85	°C

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DC ELECTRICAL CHARACTERISTICS (3.3V ± 0.3V RANGE)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT	
			Temp = -40°C to +85°C				
			MIN	TYP ¹	MAX		
V _{IK}	Input clamp voltage	V _{CC} = 3.0V; I _{IK} = -18mA		-0.85	-1.2	V	
V _{OH}	High-level output voltage	V _{CC} = 3.0 to 3.6V; I _{OH} = -100µA	V _{CC} -0.2	V _{CC}			
		V _{CC} = 3.0V; I _{OH} = -32mA	2.0	2.3			
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 100µA		0.07	0.2	V	
		V _{CC} = 3.0V; I _{OL} = 16mA		0.25	0.4		
		V _{CC} = 3.0V; I _{OL} = 32mA		0.3	0.5		
		V _{CC} = 3.0V; I _{OL} = 64mA		0.4	0.55		
I _I	Input leakage current	V _{CC} = 3.6V; V _I = V _{CC} or GND	Control pins	0.1	±1	µA	
		V _{CC} = 0 or 3.6V; V _I = 5.5V		0.1	10		
		V _{CC} = 3.6V; V _I = 5.5V	Data pins ⁴	0.1	10		
		V _{CC} = 3.6V; V _I = V _{CC}		0.1	1		
		V _{CC} = 3.6V; V _I = 0		0.1	-5		
I _{OFF}	Off current	V _{CC} = 0V; V _I or V _O = 0 to 4.5V		0.1	±100	µA	
I _{HOLD}	Bus Hold current A or B outputs	V _{CC} = 3V; V _I = 0.8V	75	130		µA	
		V _{CC} = 3V; V _I = 2.0V	-75	-200		µA	
		V _I = 0V to 3.6V; V _{CC} = 3.6V ⁶	±500			µA	
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 3.0V		10	125	µA	
I _{PU/PD}	Power up/down 3-State output current ³	V _{CC} ≤ 1.2V; V _O = 0.5V to V _{CC} ; V _I = GND or V _{CC} ; OE/OE = Don't care		1	±100	µA	
I _{OZH}	3-State output High current	V _{CC} = 3.6V; V _O = 3.0V; V _I = V _{IL} or V _{IH}		0.5	5	µA	
I _{OZL}	3-State output Low current	V _{CC} = 3.6V; V _O = 0.5V; V _I = V _{IL} or V _{IH}		0.5	-5	µA	
I _{CCH}	Quiescent supply current	V _{CC} = 3.6V; Outputs High, V _I = GND or V _{CC} , I _O = 0		0.06	0.1	mA	
I _{CCL}		V _{CC} = 3.6V; Outputs Low, V _I = GND or V _{CC} , I _O = 0		7	8.5		
I _{CCZ}		V _{CC} = 3.6V; Outputs Disabled; V _I = GND or V _{CC} , I _O = 0 ⁵		0.06	0.1		
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 3V to 3.6V; One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND		0.05	0.4	mA	

NOTES:

- All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
- This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
- This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
- Unused pins at V_{CC} or GND.
- I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
- This is the bus hold overdrive current required to force the input to the opposite state.

AC CHARACTERISTICS (3.3V ± 0.3V RANGE)

GND = 0V, t_R = t_F = 2.5ns, C_L = 50pF, R_L = 500Ω

SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT	
			T _{amb} = -40 to +85°C V _{CC} = +3.3V ± 0.3V				
			MIN	TYP	MAX		
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	0.5 0.5	1.9 1.6	3.0 2.5	ns	
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.0 1.0	2.8 2.3	4.7 3.6	ns	
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	2	1.0 1.0	3.7 2.3	5.5 4.1	ns	

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DC ELECTRICAL CHARACTERISTICS (2.5V \pm 0.2V RANGE)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT	
			Temp = -40°C to +85°C				
			MIN	TYP ¹	MAX		
V _{IK}	Input clamp voltage	V _{CC} = 2.3V; I _{IK} = -18mA		-0.85	-1.2	V	
V _{OH}	High-level output voltage	V _{CC} = 2.3 to 2.7V; I _{OH} = -100µA	V _{CC} -0.2	V _{CC}		V	
		V _{CC} = 2.3V; I _{OH} = -8mA	1.7	2.1			
V _{OL}	Low-level output voltage	V _{CC} = 2.3V; I _{OL} = 100µA		0.07	0.2	V	
		V _{CC} = 2.3V; I _{OL} = 24mA		0.3	0.5		
I _I	Input leakage current	V _{CC} = 2.7V; V _I = V _{CC} or GND	Control pins	0.1	\pm 1	µA	
		V _{CC} = 0 or 2.7V; V _I = 5.5V		0.1	10		
		V _{CC} = 2.7V; V _I = 5.5V	Data pins ⁴	0.1	10		
		V _{CC} = 2.7V; V _I = V _{CC}		0.1	1		
		V _{CC} = 2.7V; V _I = 0		0.1	-5		
I _{OFF}	Off current	V _{CC} = 0V; V _I or V _O = 0 to 4.5V		0.1	\pm 100	µA	
I _{HOLD} ⁶	Bus Hold current	V _{CC} = 2.5V; V _I = 0.8V		105		µA	
		A inputs		10		µA	
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 2.3V		10	125	µA	
I _{PU/PD}	Power up/down 3-State output current ³	V _{CC} \leq 1.2V; V _O = 0.5V to V _{CC} ; V _I = GND or V _{CC} OE/ÖE = Don't care		1	100	µA	
I _{OZH}	3-State output High current	V _{CC} = 2.7V; V _O = 2.3V; V _I = V _{IL} or V _{IH}		0.5	5	µA	
I _{OZL}	3-State output Low current	V _{CC} = 2.7V; V _O = 0.5V; V _I = V _{IL} or V _{IH}		0.5	-5	µA	
I _{CCH}	Quiescent supply current	V _{CC} = 2.7V; Outputs High, V _I = GND or V _{CC} , I _O = 0		0.04	0.1	mA	
I _{CCL}		V _{CC} = 2.7V; Outputs Low, V _I = GND or V _{CC} , I _O = 0		5.0	6.5		
I _{CCZ}		V _{CC} = 2.7V; Outputs Disabled; V _I = GND or V _{CC} , I _O = 0 ⁵		0.04	0.1		
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 2.3V to 2.7V; One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND		0.04	0.4	mA	

NOTES:

- All typical values are at V_{CC} = 2.5V and T_{amb} = 25°C.
- This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
- This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 2.5V \pm 0.2V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
- Unused pins at V_{CC} or GND.
- I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
- Not guaranteed.

AC CHARACTERISTICS (2.5V \pm 0.2V RANGE)GND = 0V, t_R = t_F = 2.5ns, C_L = 50pF, R_L = 500Ω

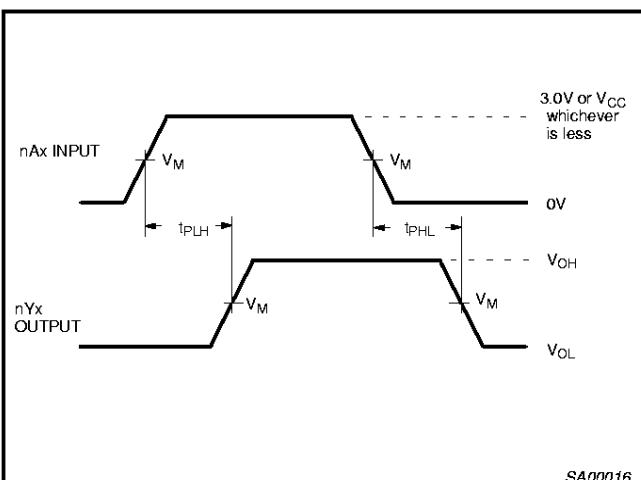
SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT	
			T _{amb} = -40 to +85°C V _{CC} = +2.5V \pm 0.2V				
			MIN	TYP	MAX		
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	0.5 0.5	2.5 1.9	4.2 3.9	ns	
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.0 1.0	3.5 2.8	6.1 4.6	ns	
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	2	1.0 1.0	2.8 3.1	5.3 4.9	ns	

2.5V/3.3V 1-to-4 address driver (3-State)

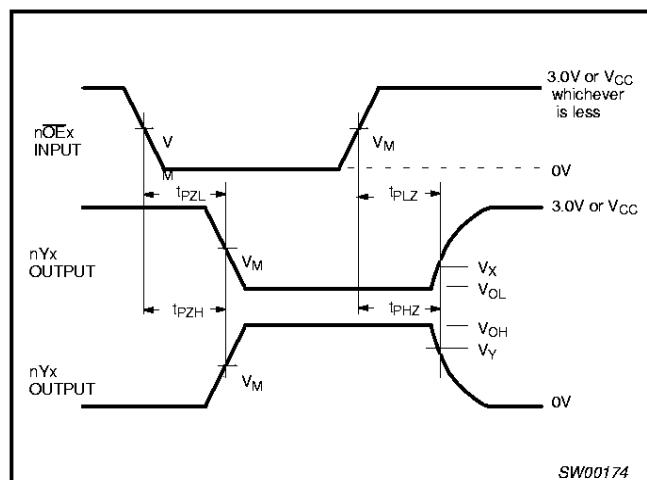
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AC WAVEFORMS

$V_M = 1.5V$ for $V_{CC} \geq 3.0V$; $V_M = V_{CC}/2$ for $V_{CC} \leq 2.7V$
 $V_X = V_{OL} + 0.3V$ for $V_{CC} \geq 3.0V$; $V_X = V_{OL} + 0.15V$ for $V_{CC} \leq 2.7V$
 $V_Y = V_{OH} - 0.3V$ for $V_{CC} \geq 3.0V$; $V_Y = V_{OH} - 0.15V$ for $V_{CC} \leq 2.7V$

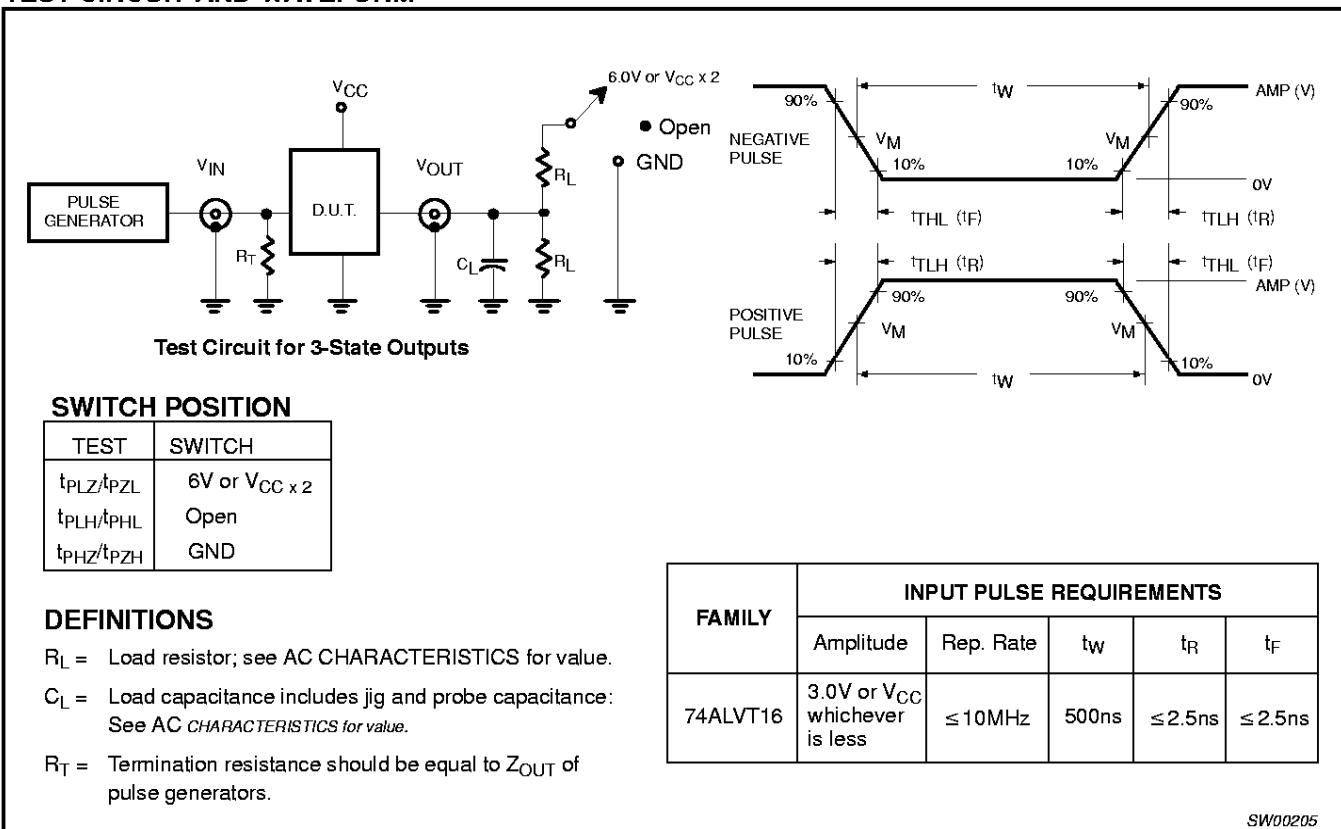


Waveform 1. Input (nAx) to Output (nYx) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORM

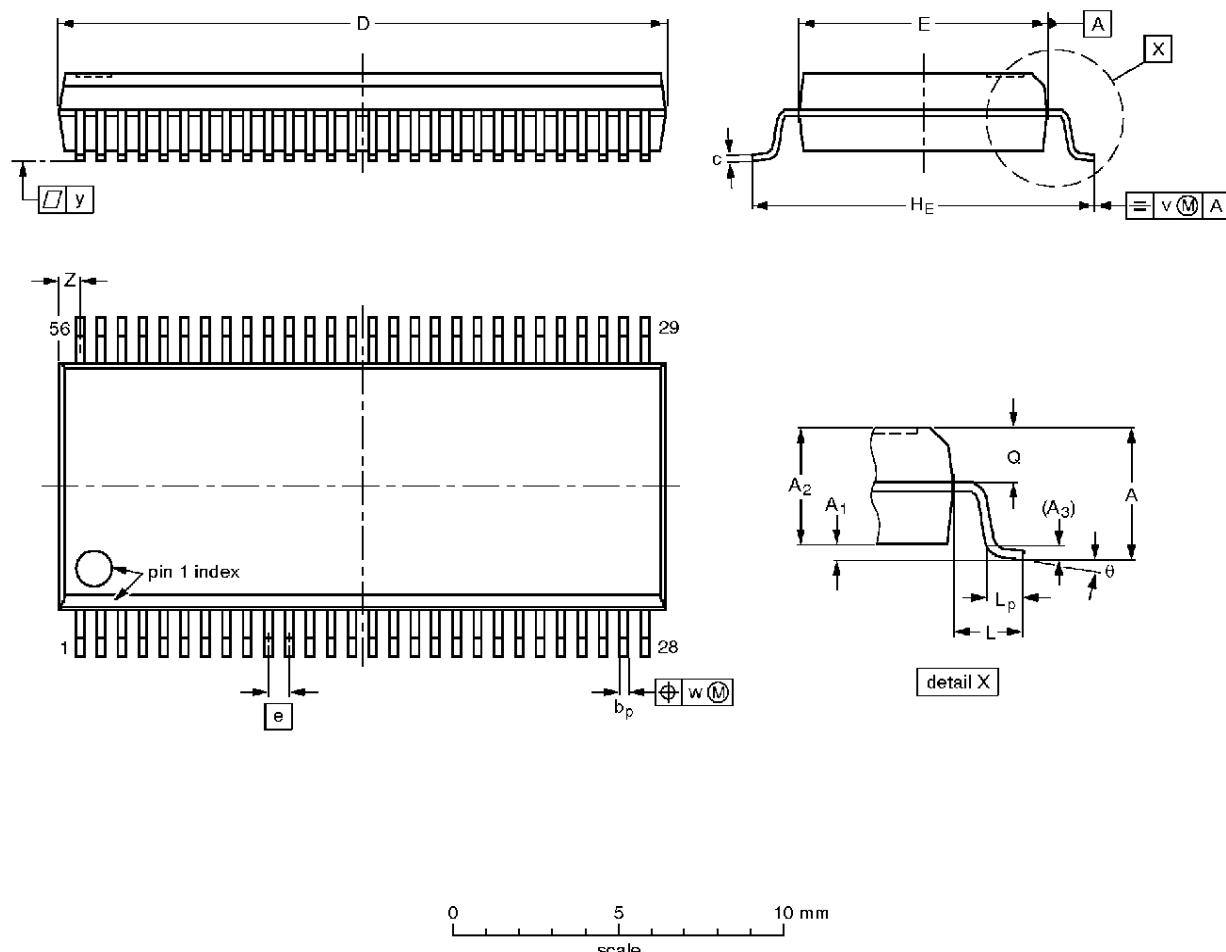


2.5V/3.3V 1-to-4 address driver (3-State)

74ALVT16344

SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm

SOT371-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	2.8 0.2	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	18.55 18.30	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

- Plastic or metal protrusions of 0.25 mm maximum per side are not included.

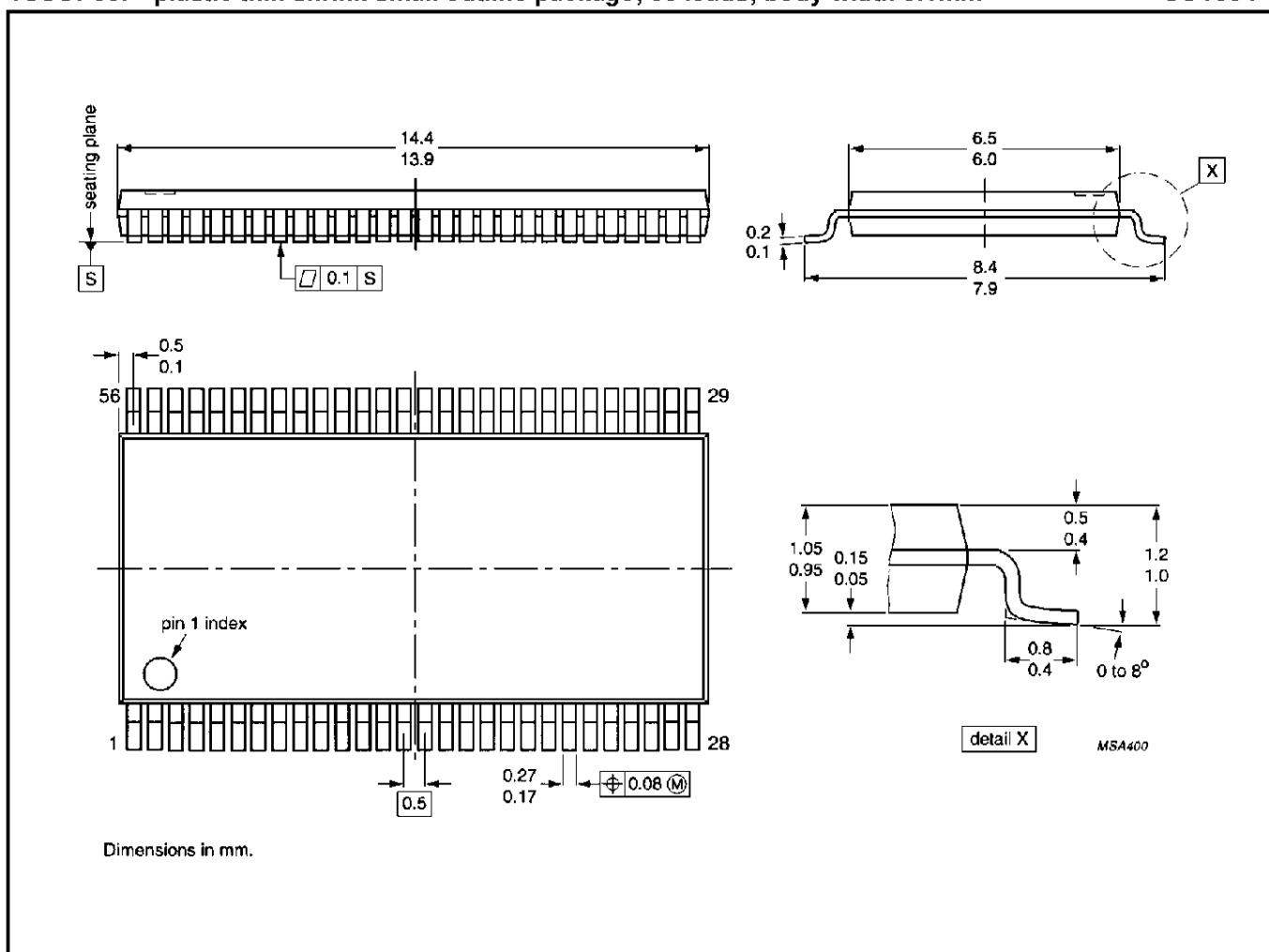
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT371-1		MO-118AB				93-11-02 95-02-04

2.5V/3.3V 1-to-4 address driver (3-State)

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TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1mm

SOT364-1



2.5V/3.3V 1-to-4 address driver (3-State)

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NOTES

2.5V/3.3V 1-to-4 address driver (3-State)

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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